

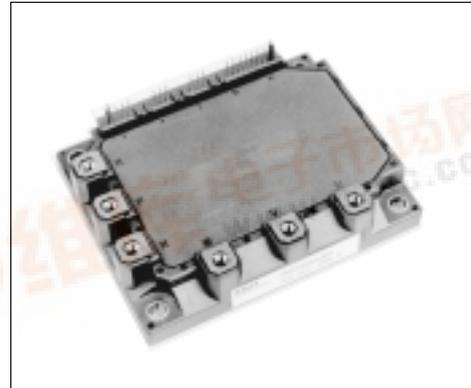
# 7MBP50RA120

## IGBT-IPM R series

1200V / 50A 7 in one-package

### Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- Compatible with existing IPM-N series packages
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



### Maximum ratings and characteristics

● Absolute maximum ratings(at Tc=25°C unless otherwise specified)

Item	Symbol	Rating		Unit		
		Min.	Max.			
DC bus voltage	V <sub>DC</sub>	0	900	V		
DC bus voltage (surge)	V <sub>DC(surge)</sub>	0	1000	V		
DC bus voltage (short operating)	V <sub>SC</sub>	200	800	V		
Collector-Emitter voltage	V <sub>CEs</sub>	0	1200	V		
DB Reverse voltage	V <sub>R</sub>	-	1200	V		
INV	Collector current	DC	I <sub>c</sub>	-	50	A
		1ms	I <sub>CP</sub>	-	100	A
		DC	-I <sub>c</sub>	-	50	A
	Collector power dissipation	One transistor	P <sub>c</sub>	-	357	W
DB	Collector current	DC	I <sub>c</sub>	-	25	A
		1ms	I <sub>CP</sub>	-	50	A
		Forward current of Diode	I <sub>F</sub>	-	25	A
	Collector power dissipation	One transistor	P <sub>c</sub>	-	198	W
Junction temperature	T <sub>j</sub>	-	150	°C		
Input voltage of power supply for Pre-Driver	V <sub>CC</sub> *1	0	20	V		
Input signal voltage	V <sub>in</sub> *2	0	V <sub>Z</sub>	V		
Input signal current	I <sub>in</sub>	-	1	mA		
Alarm signal voltage	V <sub>ALM</sub> *3	0	V <sub>CC</sub>	V		
Alarm signal current	I <sub>ALM</sub> *4	-	15	mA		
Storage temperature	T <sub>stg</sub>	-40	125	°C		
Operating case temperature	T <sub>op</sub>	-20	100	°C		
Isolating voltage (Case-Terminal)	V <sub>iso</sub> *5	-	AC2.5	kV		
Screw torque	Mounting (M5)	-	3.5 *6	N·m		
	Terminal (M5)	-	3.5 *6	N·m		

\*1 Apply V<sub>CC</sub> between terminal No. 3 and 1, 6 and 4, 9 and 7, 11 and 10.

\*2 Apply V<sub>in</sub> between terminal No. 2 and 1, 5 and 4, 8 and 7, 12,13,14,15 and 10.

\*3 Apply V<sub>ALM</sub> between terminal No. 16 and 10.

\*4 Apply I<sub>ALM</sub> to terminal No. 16.

\*5 50Hz/60Hz sine wave 1 minute.

\*6 Recommendable Value : 2.5 to 3.0 N·m

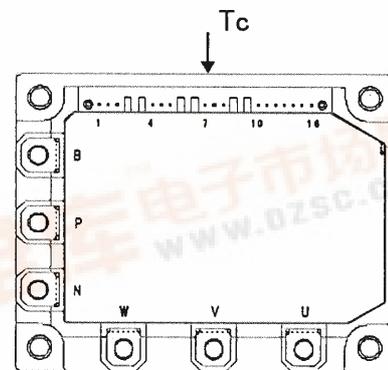


Fig.1 Measurement of case temperature

● Electrical characteristics of power circuit (at T<sub>c</sub>=T<sub>j</sub>=25°C, V<sub>CC</sub>=15V)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
INV	Collector current at off signal input	I <sub>CEs</sub>	V <sub>CE</sub> =1200V input terminal open		1.0	mA
	Collector-Emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>c</sub> =50A		2.6	V
	Forward voltage of FWD	V <sub>F</sub>	-I <sub>c</sub> =50A		3.0	V
DB	Collector current at off signal input	I <sub>CEs</sub>	V <sub>CE</sub> =1200V input terminal open		1.0	mA
	Collector-Emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>c</sub> =25A		2.6	V
	Forward voltage of Diode	V <sub>F</sub>	-I <sub>c</sub> =25A		3.3	V

● Electrical characteristics of control circuit(at Tc=Tj=25°C, Vcc=15V)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Power supply current of P-line side Pre-driver(one unit)	I <sub>ccp</sub>	fsw=0 to 15kHz Tc=-20 to 100°C *7	3	-	18	mA
Power supply current of N-line side three Pre-driver	I <sub>ccn</sub>	fsw=0 to 15kHz Tc=-20 to 100°C *7	10	-	65	mA
Input signal threshold voltage (on/off)	V <sub>in(th)</sub>	ON	1.00	1.35	1.70	V
		OFF	1.25	1.60	1.95	V
Input zener voltage	V <sub>Z</sub>	R <sub>in</sub> =20k ohm	-	8.0	-	V
Over heating protection temperature level	T <sub>COH</sub>	V <sub>DC</sub> =0V, I <sub>c</sub> =0A, Case temperature Fig.1	110	-	125	°C
Hysteresis	T <sub>CH</sub>		-	20	-	°C
IGBT chips over heating protection temperature level	T <sub>JOH</sub>	surface of IGBT chips	150	-	-	°C
Hysteresis	T <sub>JH</sub>		-	20	-	°C
Collector current protection level	INV	I <sub>oc</sub> T <sub>J</sub> =125°C	75	-	-	A
	DB	I <sub>oc</sub> T <sub>J</sub> =125°C	38	-	-	A
Over current protection delay time	t <sub>DOC</sub>	T <sub>J</sub> =25°C Fig.2	-	10	-	μs
Under voltage protection level	V <sub>UV</sub>		11.0	-	12.5	V
Hysteresis	V <sub>H</sub>		0.2	-	-	V
Alarm signal hold time	t <sub>ALM</sub>		1.5	2	-	ms
SC protection delay time	t <sub>SC</sub>	T <sub>J</sub> =25°C Fig.3	-	-	12	μs
Limiting resistor for alarm	R <sub>ALM</sub>		1425	1500	1575	ohm

\*7 Switching frequency of IPM

● Dynamic characteristics(at Tc=Tj=125°C, Vcc=15V)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Switching time (IGBT)	t <sub>on</sub>	I <sub>C</sub> =50A, V <sub>DC</sub> =600V	0.3	-	-	μs
	t <sub>off</sub>		-	-	3.6	μs
Switching time (FWD)	t <sub>rr</sub>	I <sub>F</sub> =50A, V <sub>DC</sub> =600V	-	-	0.4	

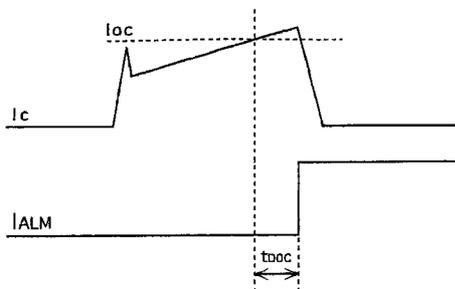


Fig.2 Definition of OC delay time

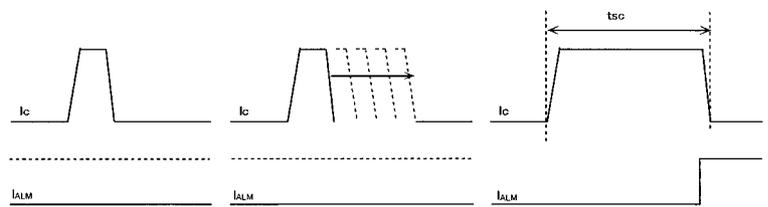


Fig.3 Definition of tsc

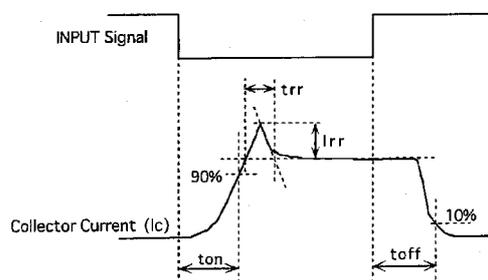


Fig.4 Definition of switching time

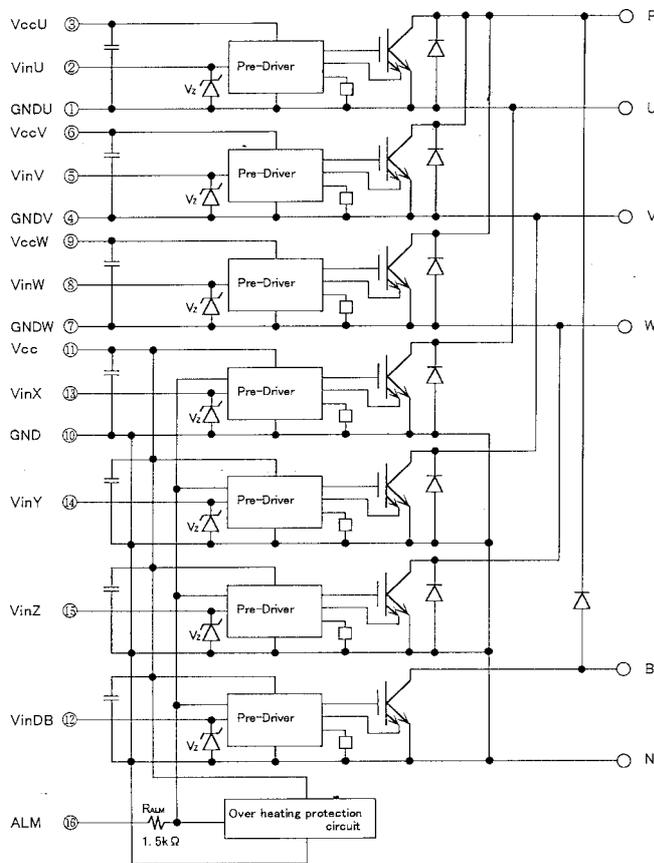
● Thermal characteristics(Tc=25°C)

Item	Symbol	Typ.	Max.	Unit		
Junction to Case thermal resistance	INV	IGBT	R <sub>th(j-c)</sub>	-	0.35	°C/W
		FWD	R <sub>th(j-c)</sub>	-	0.85	°C/W
	DB	IGBT	R <sub>th(j-c)</sub>	-	0.63	°C/W
Case to fin thermal resistance with compound	R <sub>th(c-f)</sub>	0.05	-	°C/W		

● Recommendable value

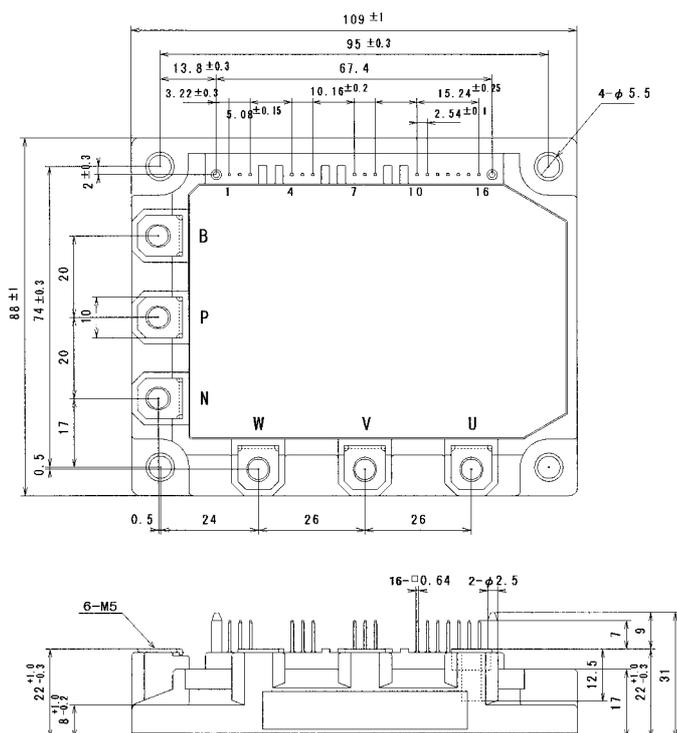
Item	Symbol	Min.	Typ.	Max.	Unit	
DC bus voltage	V <sub>DC</sub>	200	-	800	V	
Operating power supply voltage range of Pre-driver	V <sub>CC</sub>	13.5	15	16.5	V	
Switching frequency of IPM	fsw	1	-	20	kHz	
Screw torque	Mounting (M5)	-	2.5	-	3.0	N·m

Block diagram



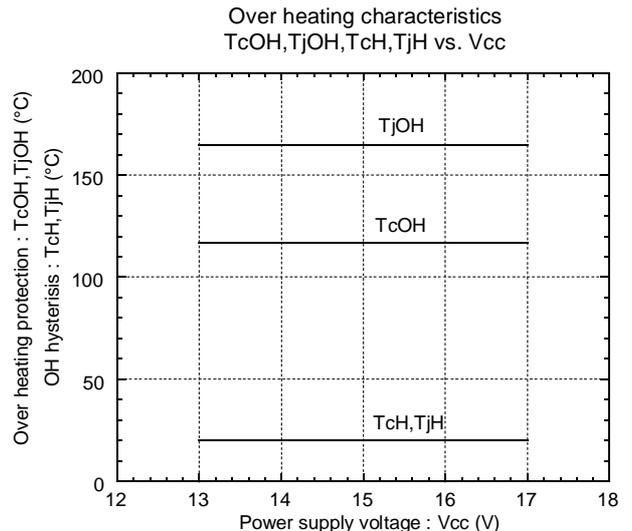
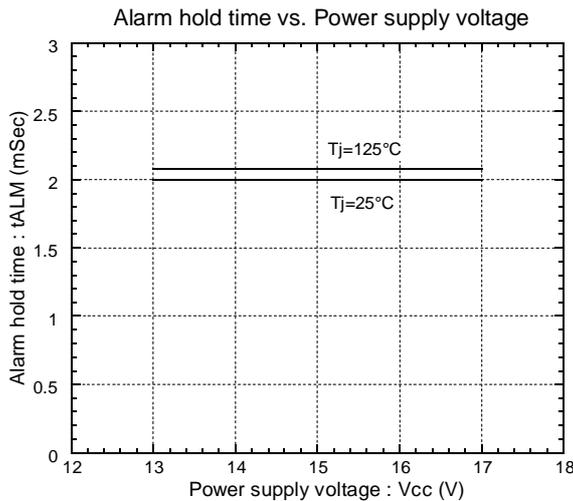
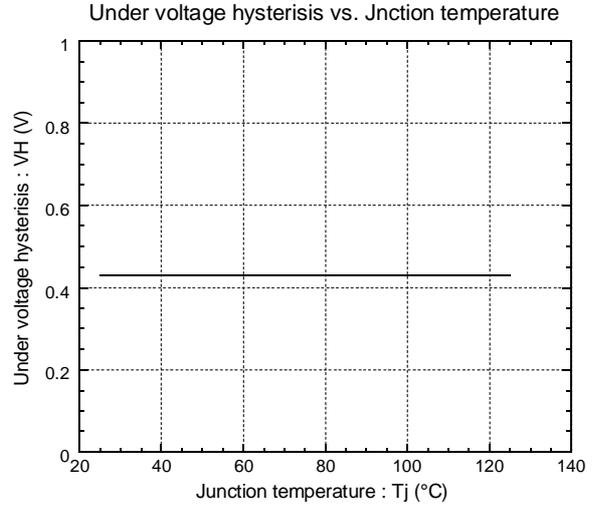
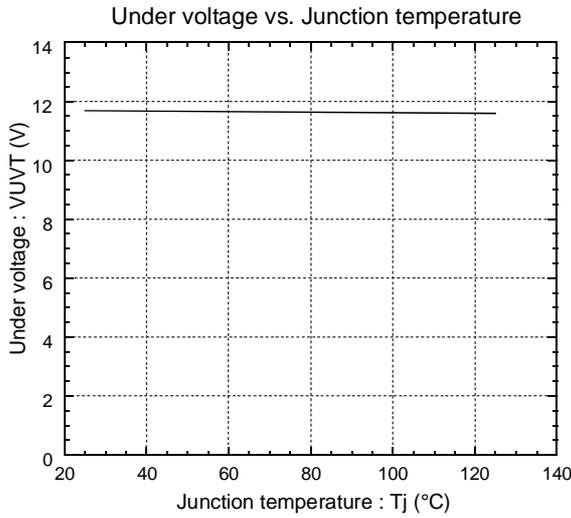
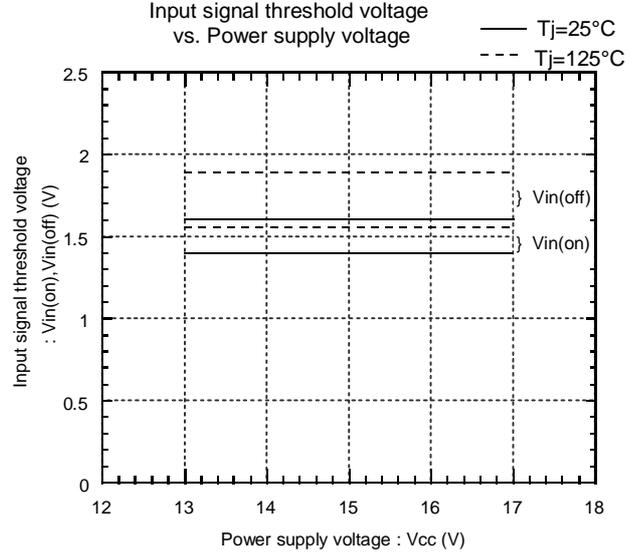
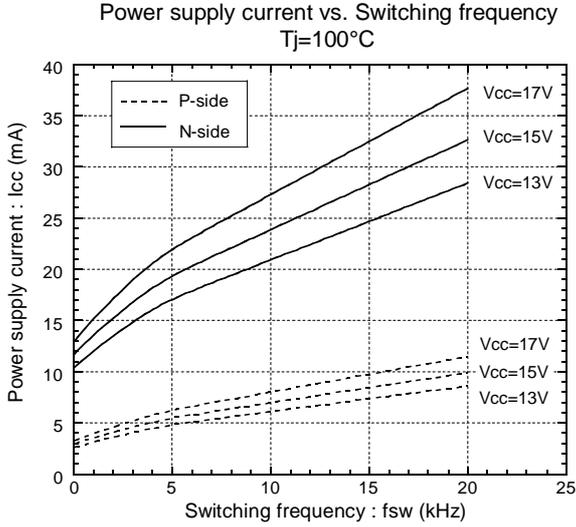
- Pre-drivers include following functions
- a) Amplifier for driver
  - b) Short circuit protection
  - c) Undervoltage lockout circuit
  - d) Over current protection
  - e) IGBT chip over heating protection

Outline drawings, mm



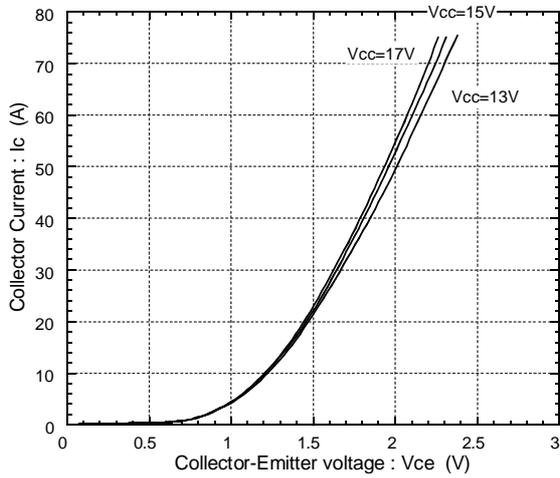
Characteristics (Representative)

Control Circuit

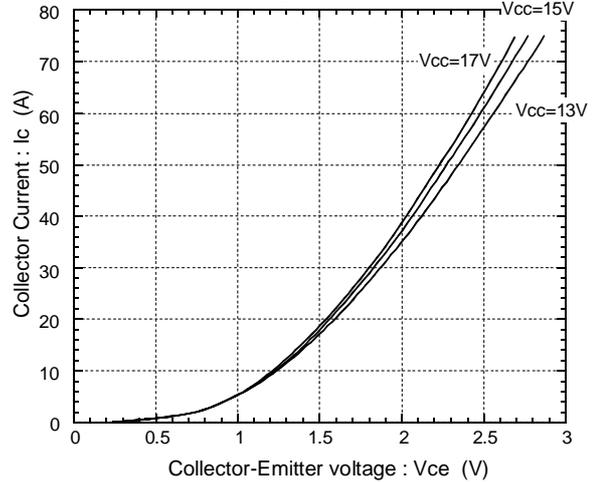


● Inverter

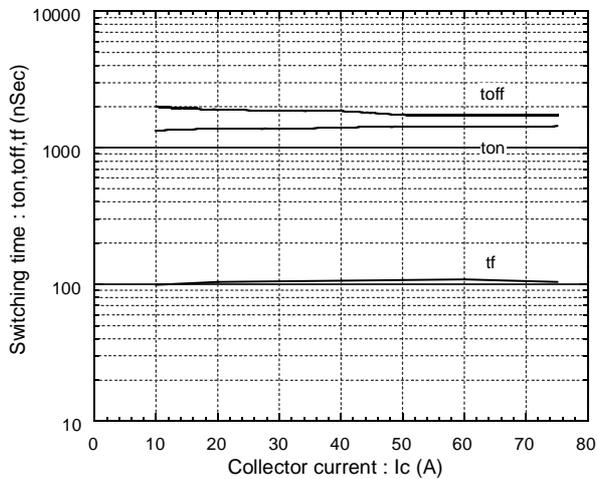
Collector current vs. Collector-Emitter voltage  
T<sub>j</sub>=25°C



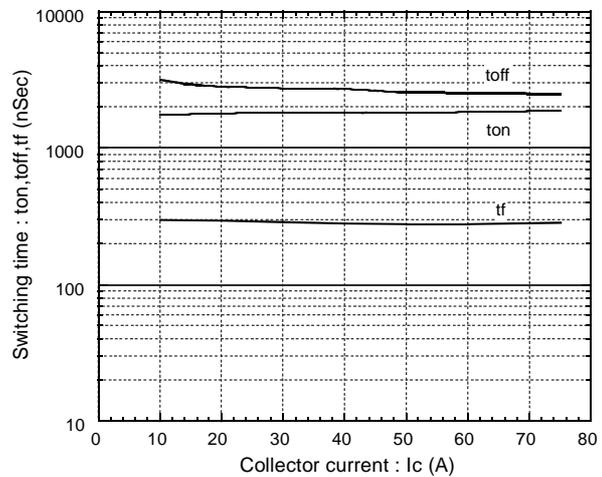
Collector current vs. Collector-Emitter voltage  
T<sub>j</sub>=125°C



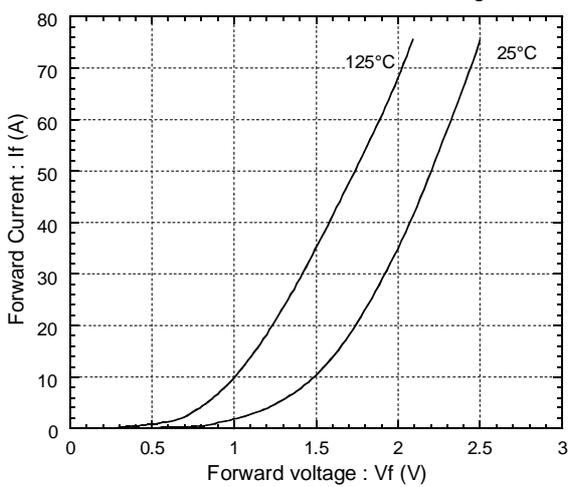
Switching time vs. Collector current  
E<sub>dc</sub>=600V, V<sub>cc</sub>=15V, T<sub>j</sub>=25°C



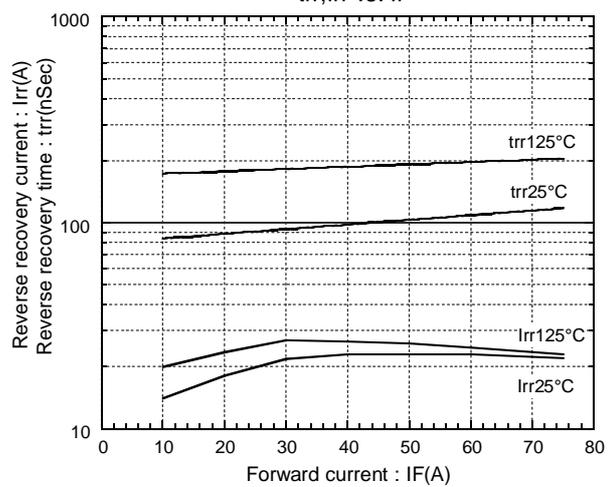
Switching time vs. Collector current  
E<sub>dc</sub>=600V, V<sub>cc</sub>=15V, T<sub>j</sub>=125°C

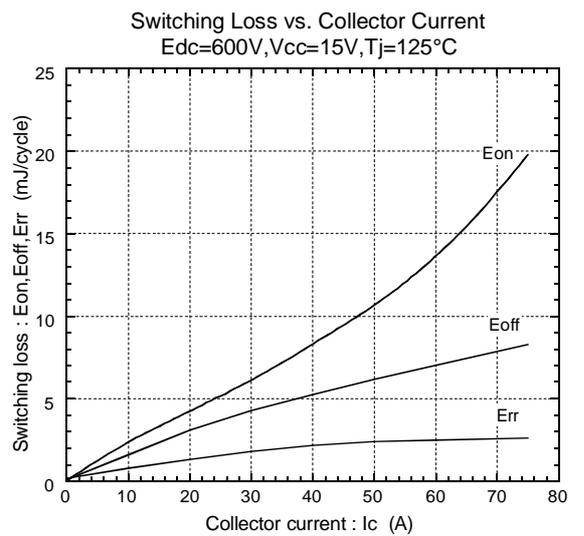
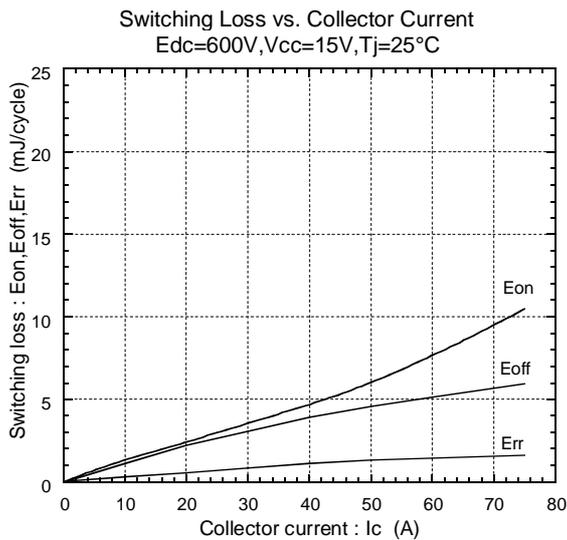
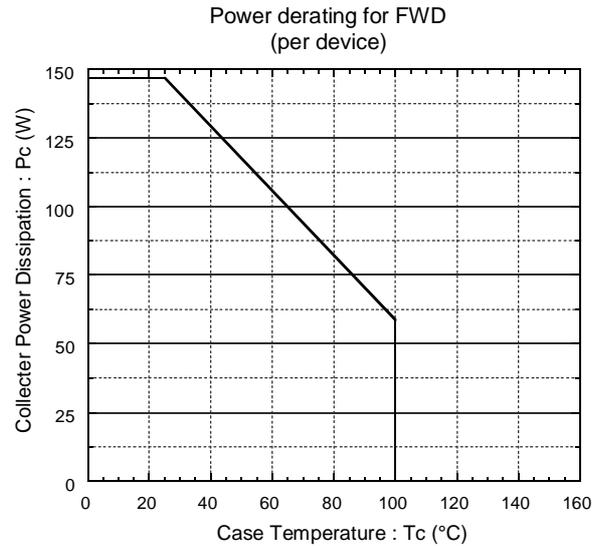
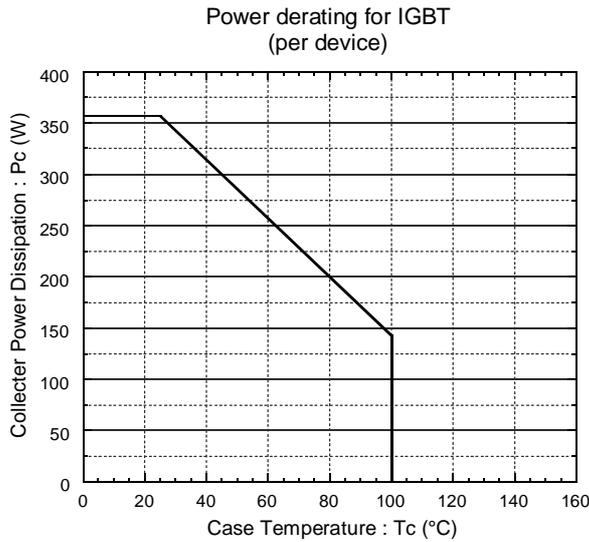
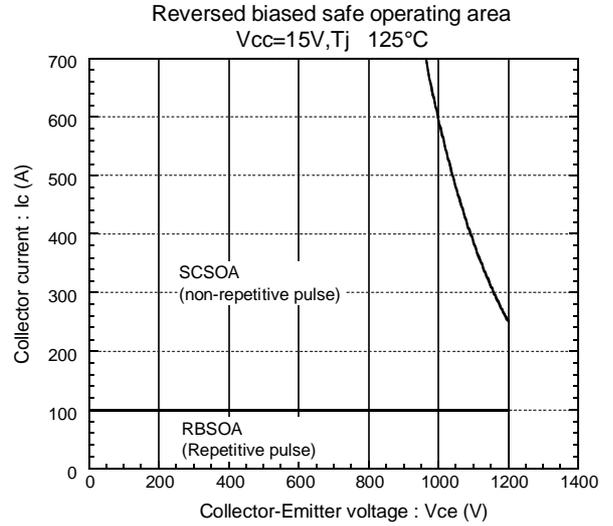
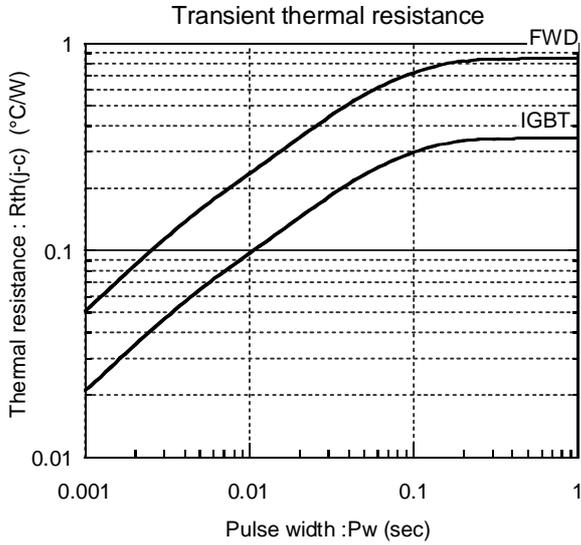


Forward current vs. Forward voltage

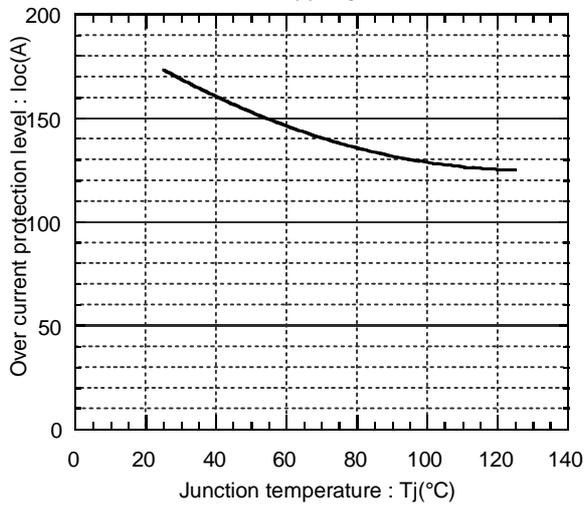


Reverse recovery characteristics  
trr, Irr vs. IF





Over current protection vs. Junction temperature  
V<sub>cc</sub>=15V



● Brake

